SMD Power Inductor

HPC5040NF-Series

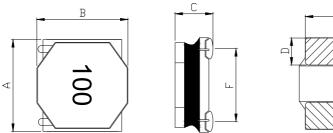
	ECN HISTORY LIST					
REV	DATE	DESCRIPTION	APPROVED	CHECKED	DRAWN	
1.0	16/03/25	新發行	楊祥忠	詹偉特	何秦芝	
備						
注						

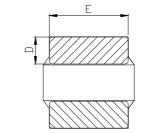
SMD Power Inductor

1. Features

- 1. This specification applies Low Profile Power Inductors.
- 2. 100% Lead(Pb) & Halogen-Free and RoHS compliant.

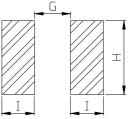
2. Dimension





Halogen-free Pb-free

Recommended Land pattern

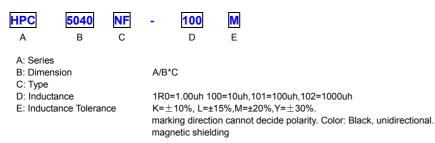


HPC5040NF ≤10 uH >10 uH >10 uH 4.95±0.2 4.95±0.2 3.9±0.2 1.3±0.3 4.2±0.2 3.7ref	Series	Inductance	A(mm)	B(mm)	C(mm)	D(mm)	E (mm)	F(mm)	
		≪10 uH	4 05 ± 0.2	4.95±0.2	3.9±0.2	1.3±0.3	4.2±0.2	3.7ref	
	HPC5040INF	>10 uH	4.95 ± 0.2		3.8±0.2				

G(mm)	H(mm)	l(mm)			
2.1 4.2 1.5					
Note · Recommend solder naste					

thickness at 0.12mm and above

3. Part Numbering



P2

HPC5040NF-Series

4. Specification

					Rated			
Part Number	Inductance Tolerar L0 (uH)		rance		Temperature	Saturation	DCR (mΩ) @25℃ ±20%.	
	@ 0 A	к	L	м	Y	current I rms (A)	current I sat (A)	± 20 %.
HPC5040NF-1R0	1.00	1	1	±20%	±30%	5.00	7.50	12
HPC5040NF-1R5	1.50	1	1	±20%	±30%	4.50	6.50	15
HPC5040NF-2R2	2.20	1	1	±20%	±30%	3.80	5.70	21
HPC5040NF-3R3	3.30	1	1	±20%	±30%	3.50	4.40	24
HPC5040NF-4R7	4.70	1	1	±20%	±30%	3.20	3.90	32
HPC5040NF-6R8	6.80	1	1	±20%	±30%	2.50	3.30	43
HPC5040NF-100	10.0	1	1	±20%	±30%	2.20	2.52	56
HPC5040NF-150	15.0	1	±15%	±20%	±30%	1.80	2.00	80
HPC5040NF-220	22.0	1	±15%	±20%	±30%	1.50	1.62	123
HPC5040NF-330	33.0	1	±15%	±20%	±30%	1.20	1.30	180
HPC5040NF-470	47.0	±10%	±15%	±20%	±30%	1.00	1.10	270
HPC5040NF-680	68.0	±10%	±15%	±20%	±30%	0.80	0.90	400
HPC5040NF-101	100	±10%	±15%	±20%	±30%	0.72	0.75	560

Note:

1. All test data referenced to 25°C ambient , Ls:100KHz/1V.

2. Testing Instrument : HP4284A,CH11025,CH3302,CH1320 ,CH1320S LCR METER / Rdc:CH502BC MICRO OHMMETER.

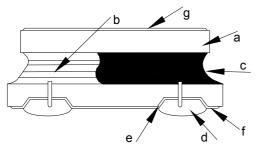
3. Heat Rated Current (Irms) will cause the coil temperature rise approximately Δt of 40°C (keep 1min.).

4. Saturation Current (Isat) will cause L0 $\,$ to drop $\,$ 30% typical. (keep quickly).

5. The part temperature (ambient + temp rise) should not exceed 125°C under worst case operating conditions. Circuit design, component, PCB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.

6. Special inquiries besides the above common used types can be met on your requirement.

5. Material List



NO	Items	Materials
а	Core	Ferrite Core
b	Wire	Copper Wire
С	Glue	Magnetic Resin
d	Solder	Lead free-Sn Cu
е	Adhesive	Ероху
f	Copper foil	Pure Copper
g	ink	Halogen-free ketone

6. Reliability and Test Condition

ltem	Performance	Test Condition
Operating temperature	-40~+125°C (Including self - temperature rise)	
Storage temperature	110~+40℃ ,50~60%RH (Product without taping) 240~+125℃ (on board)	
Electrical Performance T	est	
Inductance		HP4284A,CH11025,CH3302,CH1320,CH1320S LCR Meter.
DCR	 Refer to standard electrical characteristics list. 	CH16502,Agilent33420A Micro-Ohm Meter.
Saturation Current (Isat)	∆L30% typical.	Saturation DC Current (Isat) will cause L0 to drop $\triangle L(\%)$ (keep quickly).
Heat Rated Current (Irms)	Approximately △T40℃	Heat Rated Current (Irms) will cause the coil temperature rise △T(℃) without core loss. 1.Applied the allowed DC current(keep 1 min.). 2.Temperature measured by digital surface thermometer
Reliability Test		
Life Test		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Temperature : 125±2°C(Inductor) Applied current : rated current Duration : 1000±12hrs Measured at room temperature after placing for 24±2 hrs
Load Humidity		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity: 85±2% R.H, Temperature: 85°C±2°C Duration: 1000hrs Min. with 100% rated current
Moisture Resistance	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Measured at room temperature after placing for 24±2 hrs Preconditioning: Run through IR reflow for 2 times. (IPC/JEDEC J-STD-020DClassification Reflow Profiles 1. Baked at50°C for 25hrs, measured at room temperature after placing for 4 hrs. 2. Raise temperature to 65±2°C 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25°C in 2.5hrs. 3. Raise temperature to 65±2°C 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25°C in 2.5hrs. 3. Raise temperature to 65±2°C 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25°C in 2.5hrs, keep at 25°C 60-100%RH for 15min and vibrate at the frequency of 10 to 55 Hz to 10 Hz, measure at room temperature after placing for 1~2 hrs.
Thermal shock		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1 : -40±2℃ 30±5min Step2 : 25±2℃ ≤0.5min Step3 : 125±2℃ 30±5min Number of cycles : 500 Measured at room temperature after placing for 24±2 hrs
Vibration		Oscillation Frequency: 10 ~ 2K ~ 10Hz for 20 minutes Equipment : Vibration checker Total Amplitude:1.52mm±10% Testing Time : 12 hours(20 minutes, 12 cycles each of 3 orientations)。

TAI-TECH

Item	Performance			Test Cor	dition	
Shock	Appearance : No damage.	Тур	Peak e value (g's)	Normal duration (D) (ms)	Wave form	Velocity change (Vi)ft/sec
	Inductance : within±10% of initial value	SM	D 1500	0.5	Half-sine	15.4
	Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not	Lea	d 100	6	Half-sine	12.3
Bending	exceed the specification value	Shall be mounted on a FR4 substrate of the following dimensions: >=0805:40x100x1.2mm <0805:40x100x0.8mm Bending depth: >=0805:1.2mm <0805:0.8mm duration of 10 sec.				
Solderability	More than 95% of the terminal electrode should be covered with solder。	Solo Terr Flux Dip	perature: 245 for lead free: ime: 4±1sec	Ag3% Cu0.5% 5±5℃。 Rosin. 9.5%。		
Resistance to Soldering Heat		(emperature °C) °C) emp)	Time(s)	Temperature ramp/immers and emersion 25mm/s ±6 n	ion n rate
Terminal Strength	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles With the component mounted on a PCB with the device t be tested, apply a force (>0805:1kg, <=0805:0.5kg)to the side of a device bein tested. This force shall be applied for 60 +1 seconds. Also the force shall be applie gradually as not to apply a shock to the component being tested.				
			substrate		press tool	thick

Note : When there are questions concerning measurement result : measurement shall be made after 48 ± 2 hours of recovery under the standard condition.

7. Soldering and Mounting

(1) Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. TAI-TECH terminations are suitable for re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

(2) Solder re-flow:

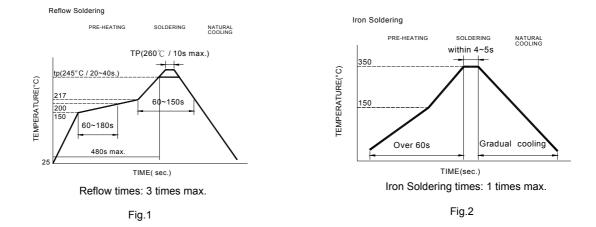
Recommended temperature profiles for re-flow soldering in Figure 1.

(3) Soldering Iron:

Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

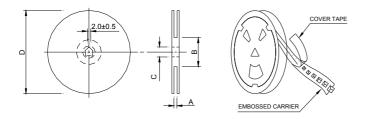
- \cdot Preheat circuit and products to 150 $^\circ\!\!\!\!\!^\circ$ \cdot Never contact the ceramic with the iron tip
- 355°C tip temperature (max) 1.0mm tip diameter (max)
 - ax)

Use a 20 watt soldering iron with tip diameter of 1.0mm
Limit soldering time to 4~5sec.



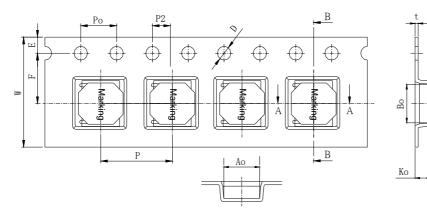
8. Packaging Information

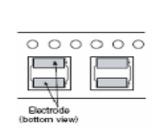
(1) Reel Dimension



Туре	A(mm)	B(mm)	C(mm)	D(mm)
13"x12mm	12.4+2/-0	80±2.0	13.5±0.5	330±3.0

(2) Tape Dimension



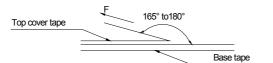


Series	Size	Bo(mm)	Ao(mm)	Ko(mm)	P(mm)	w(mm)	t(mm)	E(mm)	F(mm)	D(mm)	Po(mm)	P2(mm)
HPC	5040	5.4±0.1	5.4±0.1	4.3±0.1	8.0±0.1	12±0.3	0.4±0.1	1.75±0.1	7.5±0.1	1.5±0.1	4.0±0.1	2.00±0.1

(3) Packaging Quantity

HPC	5040
Reel	1500
Inner box	3000
Carton	12000

(4) Tearing Off Force



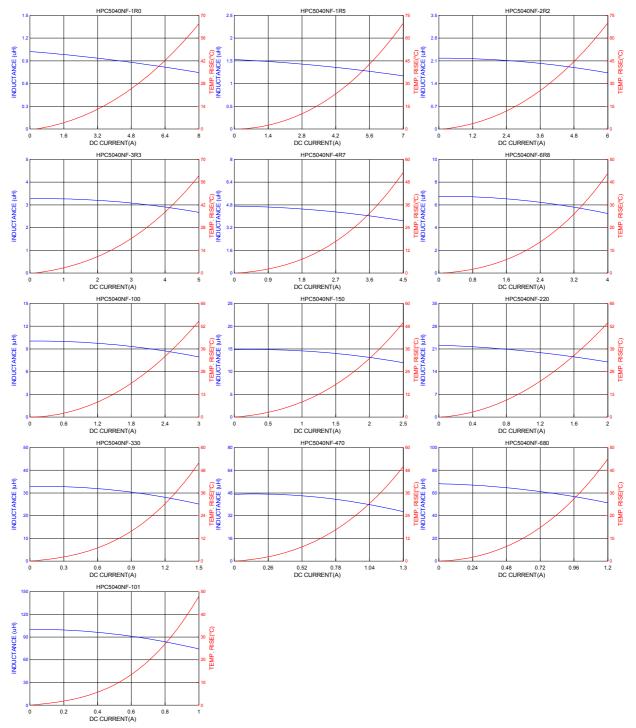
The force for tearing off cover tape is 10 to 130 grams in the arrow direction under the following conditions (referenced ANSI/EIA-481-C-2003 of 4.11 standards).

Room Temp.	Room Humidity	Room atm	Tearing Speed
(℃)	(%)	(hPa)	mm/min
5~35	45~85	860~1060	

Application Notice

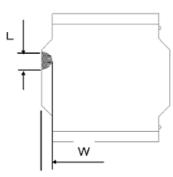
- Storage Conditions(component level) To maintain the solderability of terminal electrodes:
 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 2. Temperature and humidity conditions: Less than 40 $^\circ\!\mathrm{C}$ $\,$ and 60% RH.
- 3. Recommended products should be used within 12 months form the time of delivery.
- 4. The packaging material should be kept where no chlorine or sulfur exists in the air.
- Transportation
- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- 2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.

9. Typical Performance Curves



Core chipping

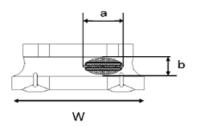
The appearance standard of the chipping size on top side, and bottom side ferrite core is listed below.



L	w
0.8mm Max.	0.8mm Max.

Void appearance tolerance Limit

Size of voids occurring to coating resin is specified below.

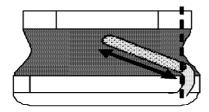


Exposed wire tolerance limit of coating resin part on product side. Size of exposed wire occurring to coating resin is specified below. 1. Width direction (dimension a): Acceptable when $a \leq w/2$.

- 1. With direction (dimension a). Acceptable when $a \ge w_A$
- Length direction (dimension b): Dimension b is not specified.
 The total area of exposed wire occurring to each sides is
 - not greater than 50% of coating resin area, and is acceptable.

External appearance criterion for exposed wire

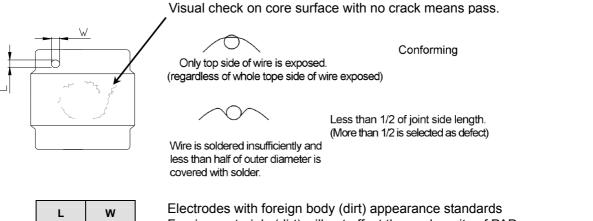
Exposed end of the winding wire at the secondary side should be 3mm and below.



0.8mm Max

0.8mm Max

Electrode appearance criterion for exposed wire



Foreign materials (dirt) will not affect the coplanarity of PAD, below the example of foreign materials (dirt) quantity ≤2PCS on single PAD. dimension range as below.





測試報告 號碼(No.) : CE/2015/B1564 日期(Date) : 2015/11/16 頁數(Page): 1 of 15 **Test Report** 西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R.O.C. (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省電市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU) 以下测試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as): SMD POWER INDUCTOR 樣品名稱(Sample Description) HPC(YHC 、 DR) 、 MDC 、 FPC(YPC) 、 FWP(YWP) 、 SPC 、 AHP 、 UHP 、 DFP 、 DHP 、 TLPC 、 樣品型號(Style/Item No.) : TLPH . TLI SERIES -收件日期(Sample Receiving Date) 2015/11/10 • 測試期間(Testing Period) 2015/11/10 TO 2015/11/16

测试结果(Test Results) :

請見下一頁 (Please refer to next pages).

Trov Chang/Manage Signed for and on Dehalf o SGS TAIWAN LTD. Chemical Laboratory - Taipei

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測試報告 Test Report ^{號碼(No}

號碼(No.): CE/2015/B1564

日期(Date): 2015/11/16

頁數(Page): 2 of 15

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

NICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.) (耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.) (慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.) 桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R.O.C. (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿還市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

测试结果(Test Results)

测试部位(PART NAME)No.1 : 整體混測(MIXED ALL PARTS)

测試項目 (Test Items)	單位 (Unit)	测試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鎘 / Cadmium (Cd)	mg/kg	参考IEC 62321-5: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n. d.
鉛 / Lead (Pb)	mg/kg	参考IEC 62321-5: 2013方法,以感應耦合 電漿原子發射光譜儀檢測. / ₩ith reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n. d.
汞 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n. d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	参考IEC 62321: 2008方法,以UV-VIS檢测. / With reference to IEC 62321: 2008 and performed by UV-VIS.	2	n. d.
六溴環十二烷及所有主要被辨別出的異構 物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	参考IEC 62321: 2008方法, 以氣相層析/質 譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	5	n. d.

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测試報告 號碼(No.): CE/2015/B1564 **Test Report**

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

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桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R.O.C. (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD,KUNJIA HI-TECH INDUSTRIAL PARK,KUN-SHAN,JIANG-SU,CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿邊市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

日期(Date): 2015/11/16

測試項目 (Test Items)	單位 (Unit)	测試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
聚氯乙烯 / PVC	**	以紅外光譜分析及焰色法檢測. / Analysis was performed by FTIR and FLAME Test.		Negative
多溴聯苯總和 / Sum of PBBs	mg/kg		-	n.d.
一溴聯苯 / Monobromobiphenyl	mg/kg	· · ·	5	n.d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n.d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n. d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	• n.d.
五溴聯苯 / Pentabromobiphenyl	mg/kg		5	n. d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n. d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n. d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n. d.
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n. d.
十溴聯苯 / Decabromobiphenyl	mg/kg	参考IEC 62321-6: 2015方法,以氣相層析/ 質譜儀檢測. / With reference to IEC	5	n. d.
多溴聯苯醚總和 / Sum of PBDEs	mg/kg	資替稅檢測,/ With reference to Inc. 62321-6: 2015 and performed by GC/MS.		n. d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n.d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n. d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n. d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n. d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n. d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n. d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n, d.
九溴聯苯醚 / Nonabromodiphenyl ether	ng/kg		5	n. d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg	· · · · · · · · · · · · · · · · · · ·	5	n.d.

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頁數(Page): 3 of 15



測試報告 Test Report ^{號碼(No.)}:

號碼(No.): CE/2015/B1564 - 6

日期(Date): 2015/11/16

頁數(Page): 4 of 15

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

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測試項目 (Test Itens)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
绨 / Antimony (Sb)	mg/kg	参考US EPA 3052方法,以感應耦合電浆原 子發射光譜儀檢測. / With reference to US EPA Method 3052. Analysis was performed by ICP-AES.	2	n. d.
鈹 / Beryllium (Be)	mg/kg	参考US EPA 3052方法,以感應耦合電漿原 子發射光譜儀檢測. / With reference to US EPA Method 3052. Analysis was performed by ICP-AES.	2	n. d.
全氣辛烷磺酸 / Perfluorooctane sulfonates (PFOS-Acid, Metal Salt, Amide)	mg/kg	參考US EPA 3550C: 2007方法, 以液相層析 /質譜儀檢測. / With reference to US EPA 3550C: 2007. Analysis was performed by LC/MS.	10	n. d.
全氟辛酸 / PFOA (CAS No.: 335-67-1)	mg/kg	参考US EPA 3550C: 2007方法, 以液相層析 /質譜儀檢測. / With reference to US EPA 3550C: 2007. Analysis was performed by LC/MS.	10	n. d.
鹵素 / Halogen			***	
鹵素 (氟) / Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg		50	n.d.
鹵素(氣) / Halogen-Chlorine(C1) (CAS No.: 22537-15-1)	mg/kg	参考BS EN 14582:2007,以離子層析儀分 析. / With reference to BS EN	50	n. d.
鹵素 (溴) / Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	14582:2007. Analysis was performed by IC.	50	n. d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg	· · · · · · · · · · · · · · · · · · ·	50	n. d.

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SGS Taivvari Ltd. 台湾 徐駿井技殿 份有限公司 125, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 衛北市正殿區新北產樂園區五優七路25號



測試報告 Test Report^號

號碼(No.): CE/2015/B1564

日期(Date): 2015/11/16

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
鄰苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg		50	n. d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg		50	n. d.
鄰苯二甲酸二(2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n. d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84-69- 5)	mg/kg	參考IEC 62321-8 (111/321/CD),以氣相層 析儀/質譜儀檢測之. / With reference to	50	n.d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761- 40-0; 68515-49-1)	mg/kg	IEC 62321-8 (111/321/CD). Analysis was performed by GC/MS.	50	n. d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553- 12-0; 68515-48-0)	mg/kg		50	n, d,
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n. d.
鄰苯二甲酸二正己酯 / DNHP (Di-n- hexyl phthalate) (CAS No.: 84-75-3)	mg/kg		50	n. d.

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日期(Date): 2015/11/16

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西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

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備註(Note):

- 1. mg/kg = ppm; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. **= Qualitative analysis (No Unit) 定性分析(無單位)
- 6. Negative = Undetectable 陰性(未偵測到); Positive = Detectable 陽性(已偵測到)
- 7. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個別單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

PFOS參考資訊(Reference Information): 持久性有機污染物 POPs - (EU) 757/2010

PFOS濃度在物質或製備中不得超過0.001%(10ppm),在半成品、成品或零部件中不得超過0.1%(1000ppm),在紡織品或塗 層材料中不得超過1µg/m²。

(Outlawing PFOS as substances or preparations in concentrations above 0.001% (10ppm), in semi-finished products or articles or parts at a level above 0.1%(1000ppm), in textiles or other coated materials above lug/m^2 .)

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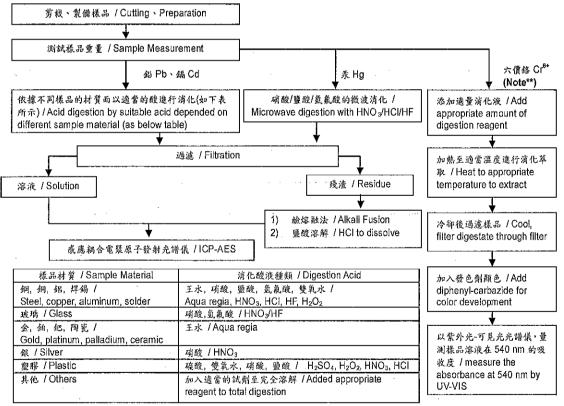
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1) 根據以下的流程圖之條件,樣品已完全溶解。(六價鋒測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr6+ test method excluded) 2)

- 测试人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 测試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang 3)



Note** (For IEC 62321)

- (1) 針對非金屬材料加入鹼性消化液,加熱至 90~95℃萃取. / For non-metallic material, add alkaline digestion reagent and heat to 90~95°C.
- (2) 針對金屬材料加入純水,加熱至沸腾萃取. / For metallic material, add pure water and heat to boiling.

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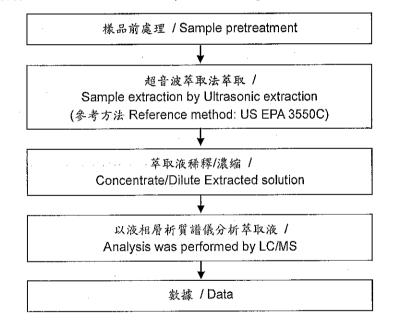
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全氟辛酸/全氟辛烷磺酸分析流程圖 / PFOA/PFOS analytical flow chart

■ 测試人員:翁賜彬 / Name of the person who made measurement: Roman Wong

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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測試報告 ^{號碼(No.)}: CE/2015/B1564 日期(Date): 2015/11/16 **Test Report**

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- 根據以下的流程圖之條件,樣品已完全溶解。 / These samples were dissolved totally by pre-conditioning method according to below flow chart.
- 测試入員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 测試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang

元素以 ICP-AES 分析的消化流程圖 (Flow Chart of digestion for the elements analysis performed by ICP-AES) 剪裁、製備樣品 / Cutting、Preparation T 測試樣品重量 / Sample Measurement 依據不同樣品的材質而以適當的酸進行消化(如下表所示)/Acid digestion by suitable acid depended on different sample material (as below table) 過濾 / Filtration T 殘渣 / Residue 溶液 / Solution 1) 鹼熔融法 / Alkali Fusion 2) 鹽酸溶解 / HCI to dissolve 感應耦合電漿原子發射光譜儀 / ICP-AES 王水,硝酸,鹽酸,氫氟酸,雙氧水 / 鋼,銅,鋁,焊錫 / Steel, copper, aluminum, solder Aqua regia, HNO₃, HCl, HF, H₂O₂ 硝酸,氫氟酸 / HNO₃/HF 玻璃 / Glass 金,鉑,鉅,陶瓷 / Gold, platinum, palladium, ceramic 王水 / Aqua regia 硝酸 / HNO3 銀 / Silver 硫酸,雙氧水,硝酸,鹽酸 / H2SO4, H2O2, HNO3, HCI 塑膠 / Plastic 加入適當的試劑至完全溶解 / Added appropriate 其他 / Others reagent to total digestion

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測試報告 Test Report 號碼(No.): CE/2015/B1564

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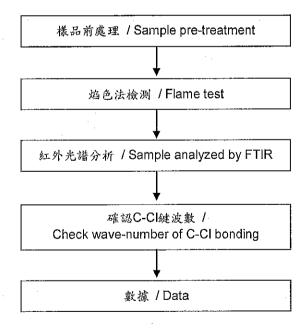
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聚氯乙烯物質判定分析流程圖 1

Analysis flow chart for determination of PVC in material

■ 測試人員:林建宇 / Name of the person who made measurement: Roy Lin

■ 测试負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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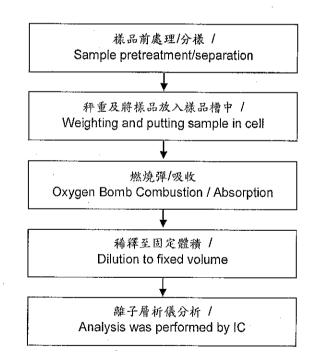
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鹵素分析流程圖 / Analytical flow chart of halogen content

■ 測試人員:陳恩臻 / Name of the person who made measurement: Rita Chen

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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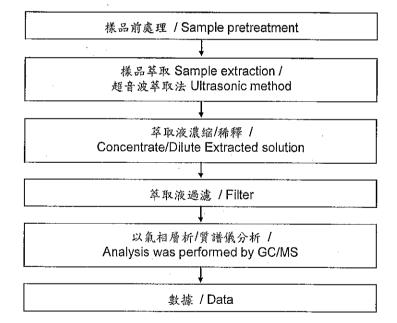
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六溴環十二烷分析流程圖 / HBCDD analytical flow chart

■ 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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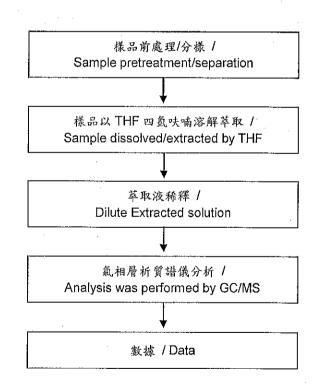
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可塑劑分析流程圖 / Analytical flow chart of phthalate content

■ 测試人員:徐毓明 / Name of the person who made measurement: Andy Shu

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang

【测試方法/Test method: IEC 62321-8】



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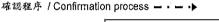
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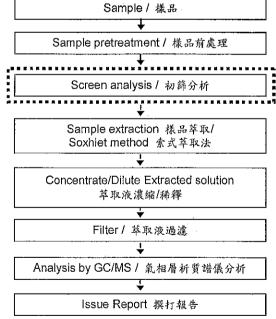
多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

■ 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong

■ 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang

初次测试程序 / First testing process →→ 選擇性篩檢程序 / Optional screen process =======





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測試報告

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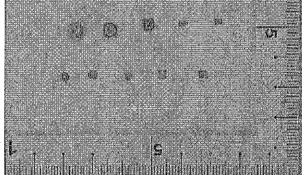
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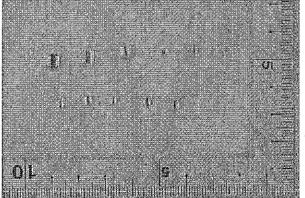
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